NSN 5961-01-252-6150

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-252-6150 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 10.00 milliamperes reverse current, dc all semiconductor device diode **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation all semiconductor device diode **Capacitance Rating In Picofarads:** 1.0 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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